

## RESEARCH ARTICLE

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11, 3744**RbPbPS<sub>4</sub>: a promising IR nonlinear optical material achieved by lone-pair-cation-substitution-induced structure transformation†**A-Yang Wang,<sup>‡a,b,c</sup> Sheng-Hua Zhou,<sup>‡a,d</sup> Mao-Yin Ran,<sup>a,b,e</sup> Bingxuan Li,<sup>a,b</sup>  
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When stereochemically-active-lone-pair (SCALP) cations are introduced into chalcogenide systems, it is beneficial to produce a remarkable second-harmonic generation (SHG) response ( $d_{\text{eff}}$ ), but it also causes a narrow band gap ( $E_g$ ), which ultimately results in negative two-photon and free-carrier absorption. Hence, how to obtain a wide  $E_g$  (>2.33 eV) while maintaining a strong  $d_{\text{eff}}$  remains a significant challenge in this domain. In this work, Rb is partially replaced by SCALP Pb in the known ternary centrosymmetric (CS)  $\text{Rb}_3\text{PS}_4$  (space group:  $Pnma$ ). This results in a quaternary non-centrosymmetric (NCS)  $\text{RbPbPS}_4$  (space group:  $P2_12_12_1$ ), which possesses distinct 2D  $[\text{PbPS}_4]^-$  layers and  $\text{Rb}^+$  occupies the interlayer spaces as the counter cations. Notably,  $\text{RbPbPS}_4$  exhibits a promising overall performance, including strong  $d_{\text{eff}}$  ( $2.5 \times \text{AgGaS}_2$ ), wide IR transmittance cutoff edge (up to 18.1  $\mu\text{m}$ ) along with the large  $E_g$  (2.75 eV), resulting in an improved laser-induced damage threshold ( $7.5 \times \text{AgGaS}_2$ ). Theoretical calculations further indicated that the favorable balance between strong  $d_{\text{eff}}$  and large  $E_g$  in  $\text{RbPbPS}_4$  can be attributed to the synergies of the  $[\text{PbS}_7]$  and  $[\text{PS}_4]$  nonlinear optical (NLO)-active units. This study not only presents a high-performance Pb-based IR-NLO candidate but also underscores the effectiveness of partial substitution of SCALP cations in inducing a CS-to-NCS structural transformation.

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**Introduction**

Nonlinear optical (NLO) materials have garnered unprecedented attention in laser science and technology because of their ability to facilitate frequency conversion in solid-state laser devices.<sup>1</sup> As widely recognized, an excellent NLO candidate should meet several crucial prerequisites: a sufficient second-harmonic generation (SHG) intensity ( $d_{\text{eff}}$ ), a large energy gap ( $E_g$ ), a wide optical transparent window, a moderate birefringence ( $\Delta n$ ), chemical stability, and availability for

obtaining large single crystals.<sup>2</sup> In the infrared (IR) region, numerous vital fields, including optoelectronic instruments, resource exploration, and remote laser communication, has sparked widespread attention and interest. Despite the strong  $d_{\text{eff}}$  exhibited by commercial IR-NLO crystals such as  $\text{AgGaQ}_2$  ( $Q = \text{S}, \text{Se}$ )<sup>3</sup> and  $\text{ZnGeP}_2$ ,<sup>4</sup> which make them suitable for applications in the IR region, they still suffer from limitations in high-power laser systems due to their low laser-induced damage thresholds (LIDT) or detrimental two-photon absorption, primarily attributed to their small  $E_g$ . However, integrating these optical performances into a single crystal is extremely challenging because they typically depend on competing structural requirements, such as the trade-off between wide  $E_g$  and strong  $d_{\text{eff}}$ .<sup>5</sup> Therefore, it is of scientific and technological significance to explore new IR-NLO crystals with outstanding comprehensive performance to overcome these challenges.

In addition to the performance prerequisites mentioned above, a prerequisite of an IR-NLO crystal is that it has a non-centrosymmetric (NCS) structure.<sup>6</sup> The addition of stereochemically-active-lone-pair (SCALP) cations, like  $\text{As}^{3+}$ ,  $\text{Sb}^{3+}$ ,  $\text{Bi}^{3+}$ ,  $\text{Sn}^{2+}$ , and  $\text{Pb}^{2+}$ , to chalcogenide systems has attracted the most attention among all the feasible approaches for creating IR-NLO materials because the majority of these chalcogenides exhibit exceptional IR-NLO performances.<sup>7</sup> Among these

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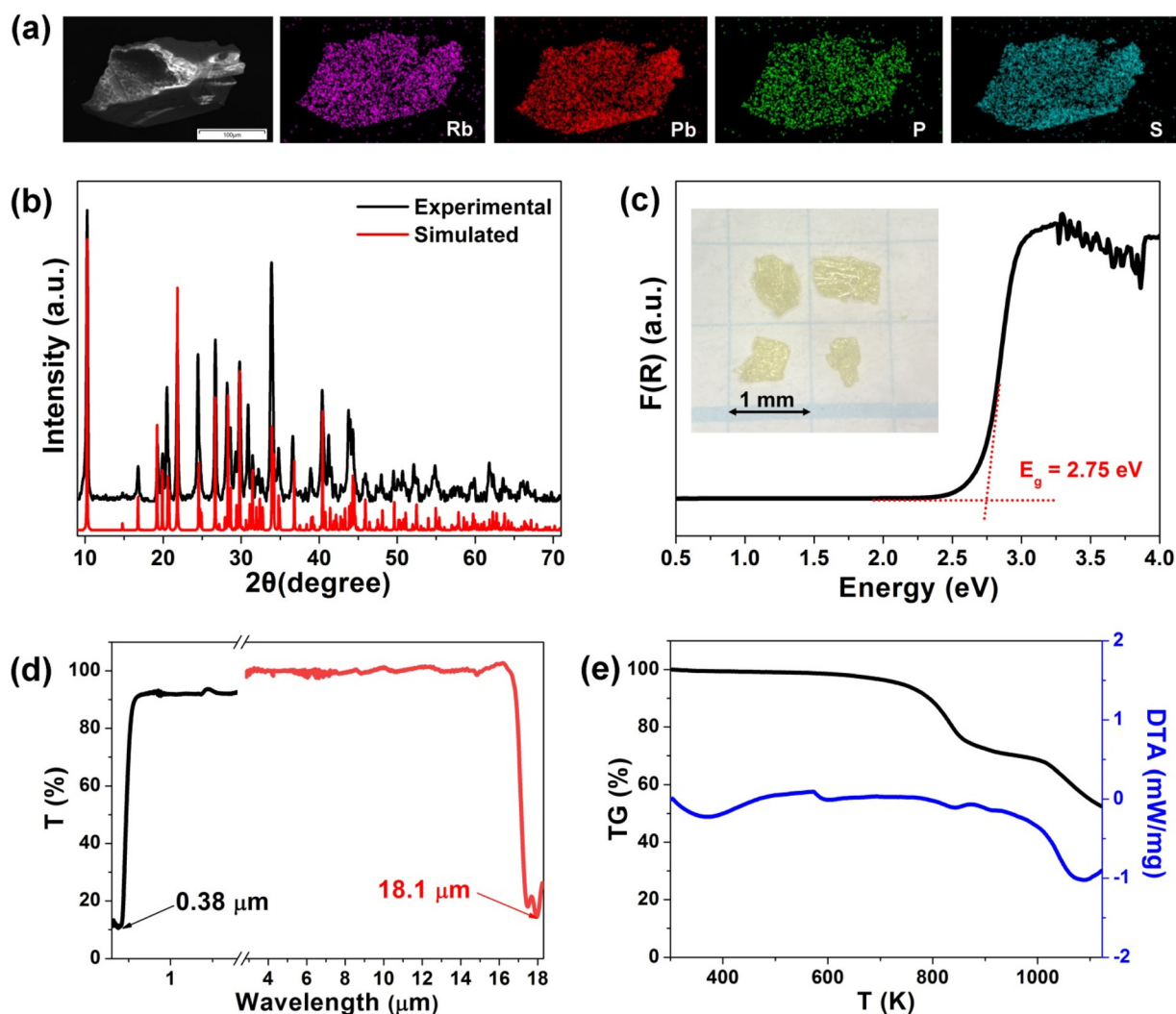
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cations,  $\text{Pb}^{2+}$  makes a significant contribution to the  $d_{\text{eff}}$  but adversely affects the optical  $E_g$ .<sup>8</sup> As is known, narrow energy gaps ( $E_g < 2.33$  eV) are unable to mitigate some harmful two-photon or free-carrier absorption under fundamental 1064 nm laser sources.<sup>9</sup> Therefore, achieving a wide  $E_g$  ( $>2.33$  eV) while maintaining a strong  $d_{\text{eff}}$  remains a significant challenge in Pb-based IR-NLO material design. On the other hand, partial chemical substitution in view of known centrosymmetric (CS) parent structures has shown to be a straightforward but incredibly successful approach in recent years for the design and synthesis of novel high-performance SCALP-based IR-NLO crystals.<sup>10</sup> Successful examples include NCS  $\text{Ba}_2\text{As}_2\text{Se}_5$  (parent structure: CS  $\text{Ba}_2\text{GaAsSe}_5$ ),<sup>11</sup> NCS  $\text{K}_2\text{Ag}_3\text{Sb}_3\text{S}_7$  (parent structure: CS  $\text{K}_2\text{Sb}_4\text{S}_7$ ),<sup>12</sup> NCS  $\text{ABiP}_2\text{S}_6$  ( $A = \text{K}, \text{Rb}$ ) (parent structure: CS  $\text{A}_4\text{P}_2\text{S}_6$ ),<sup>13,14</sup> NCS  $\text{Sn}_7\text{Br}_{10}\text{S}_2$  (parent structure: CS  $\text{SnBr}_2$ ),<sup>15</sup>  $\text{Sr}_{2-x}\text{Pb}_x\text{GeSe}_4$  (parent structure: NCS  $\text{Sr}_2\text{GeSe}_4$ ),<sup>16</sup> and NCS  $\text{Pb}_4\text{SeBr}_6$  (parent structure: CS  $\text{PbBr}_2$ ).<sup>17</sup> Considering these

factors, our focus lies in identifying suitable CS parent structures with wide  $E_g$  and achieving CS-to-NCS structural transformation by introducing SCALP Pb for partial chemical substitution. This approach aims to obtain NCS materials with excellent, well-balanced IR-NLO performance.

The ternary chalcophosphate  $\text{Rb}_3\text{PS}_4$  has piqued our interest due to its CS space group of  $Pmna$  and unique zero-dimensional (0D) cluster structure.<sup>18</sup> By incorporating distorted Pb-based motifs, it is possible to disrupt symmetric centers, leading to structural reconstruction and the formation of NCS compounds. Furthermore,  $\text{Rb}_3\text{PS}_4$  boasts a sufficiently large  $E_g$  ( $>3.5$  eV), which can help offset the potential decrease in  $E_g$  resulting from the introduction of SCALP  $\text{Pb}^{2+}$  cations into new compounds. Following this approach, we have designed and synthesized the quaternary Pb-based thiophosphate  $\text{PbPbPS}_4$ , featuring a two-dimensional (2D) layered structure composed of  $[\text{PbS}_7]$  polyhedra and  $[\text{PS}_4]$  tetrahedra.



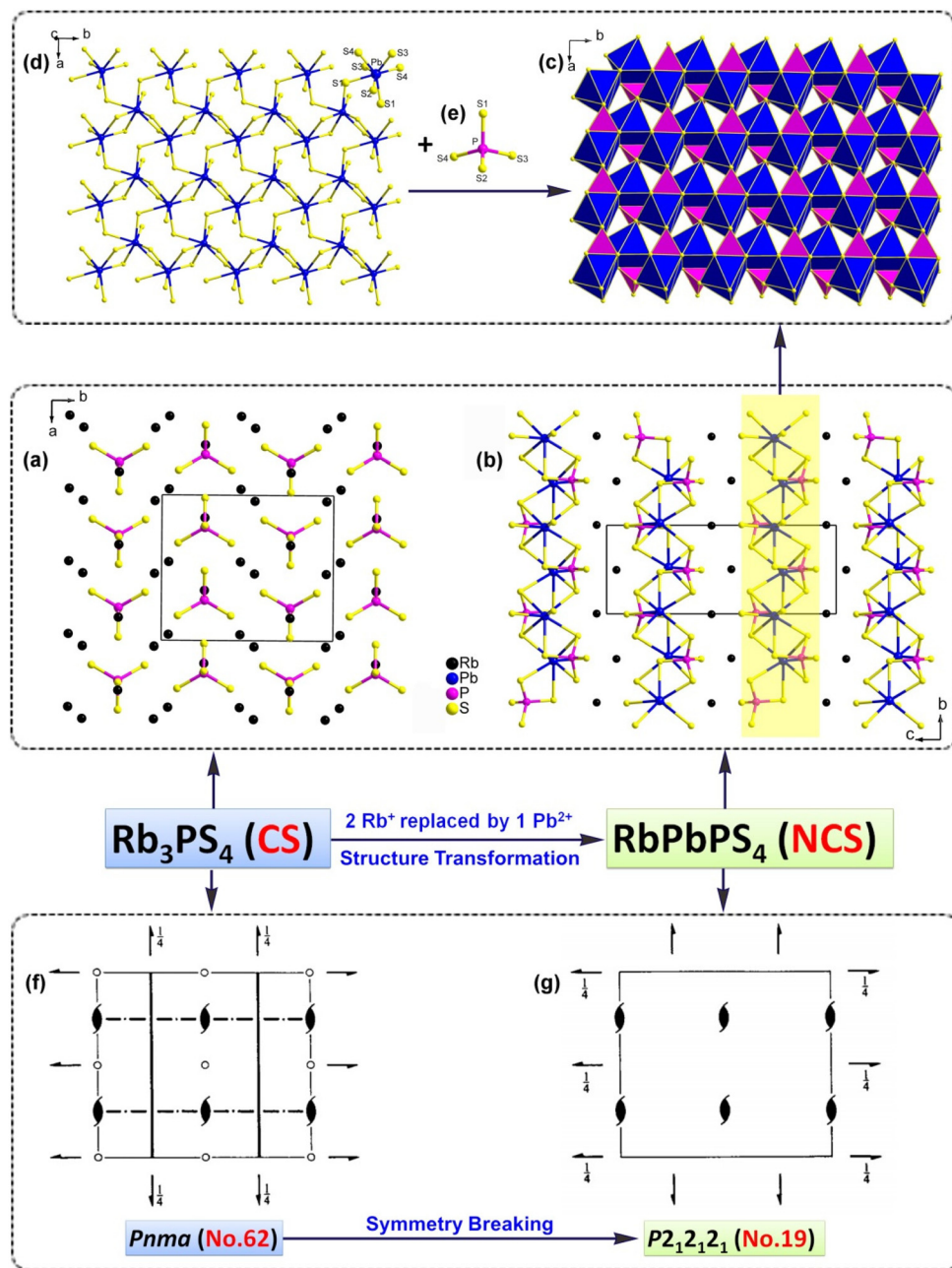
**Fig. 1** Experimental characterization results of  $\text{PbPbPS}_4$ : (a) SEM image and corresponding elemental distribution maps; (b) experimental (black) and simulated (red) powder XRD patterns; (c) UV-vis-NIR spectrum (inset: photograph of the title crystals); (d) optical transmittance spectrum; (e) TG-DTA test curves.



Remarkably, RbPbPS<sub>4</sub> demonstrates comprehensive IR-NLO performance, including a strong  $d_{\text{eff}}$  (3.2 times that of AgGaS<sub>2</sub>), one of the widest  $E_g$  among Pb-based NCS chalcogenides, high LIDT (7.5 times that of AgGaS<sub>2</sub>), a broad transmittance range (up to 18.1  $\mu\text{m}$ ), and suitable  $\Delta n$  (0.112@2050 nm). In this report, we provide detailed insights into the CS-to-NCS structural transformation and the related optical properties of RbPbPS<sub>4</sub>. Additionally, theoretical calculations are employed to further elucidate its linear optical and NLO performances.

## Results and discussion

There are reports of RbPbPS<sub>4</sub>'s crystal structure exhibiting two distinct phases.<sup>19</sup> However, we meticulously determined the structure of the title compound to explore the intricate relationship between its NCS crystal structure and NLO properties. Light yellow lamellar crystals of RbPbPS<sub>4</sub>, with sizes reaching the millimeter level, were grown using a simple boron–chalcogen method.<sup>20</sup> This method differs from previously reported techniques, which often necessitate complex



**Fig. 2** Structure evolution from ternary CS Rb<sub>3</sub>PS<sub>4</sub> to quaternary NCS RbPbPS<sub>4</sub>: view of the 2D layered structures of (a) Rb<sub>3</sub>PS<sub>4</sub> and (b) RbPbPS<sub>4</sub> along the *ab* and *bc* plane, respectively; (c) a polyhedral 2D layer [PbPS<sub>4</sub>]<sup>-</sup> composed of (d) 2D Pb–S layer and (e) discrete tetrahedral [PS<sub>4</sub>] motifs; (f and g) spatial symmetry operation changing from CS *Pnma* (no. 62) to NCS *P2<sub>1</sub>2<sub>1</sub>2<sub>1</sub>* (no. 19).



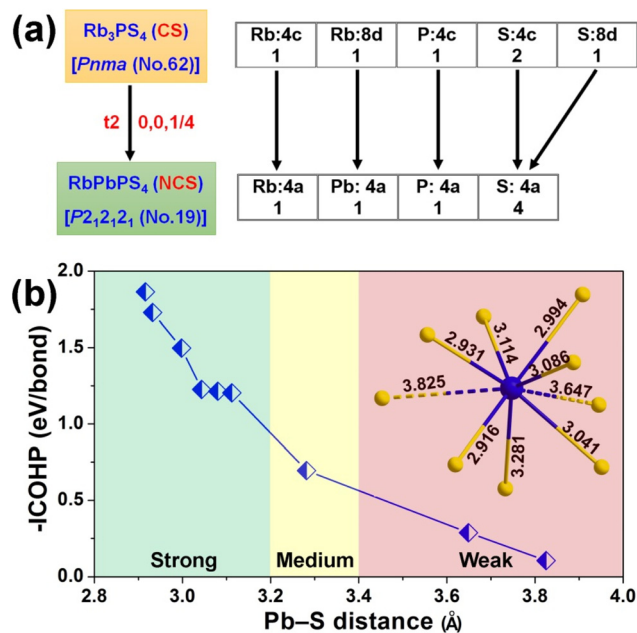
experimental procedures or involve the use of costly and hazardous elemental Rb as a raw material. Elemental distribution maps indicate that Rb, Pb, P, and S are uniformly distributed throughout the crystals (Fig. 1a). Furthermore, EDX results confirmed that the average molar ratios of the title compound correspond to the formula determined by single-crystal XRD analysis (Fig. S1†). Powder XRD testing validated the phase purity of the title compound, as the experimental patterns closely matched the simulated data obtained from single-crystal XRD analyses (Fig. 1b). The UV-vis diffuse reflectance spectrum of RbPbPS<sub>4</sub> is depicted in Fig. 1c, and absorption data were derived using the Kubelka–Munk equation.<sup>21</sup> With an experimental optical  $E_g$  of 2.75 eV, RbPbPS<sub>4</sub> exhibits the second-highest recorded value among Pb-based IR-NLO chalcogenides. Additionally, RbPbPS<sub>4</sub> demonstrates broad optical transparency across the 0.38–18.1  $\mu\text{m}$  range (Fig. 1d). Thermogravimetric-differential thermal analysis (TG-DTA) was employed to assess the thermal stability of RbPbPS<sub>4</sub>, revealing that the compound remains stable below 700 K (Fig. 1e).

In the asymmetric unit, ternary Rb<sub>3</sub>PS<sub>4</sub> has two independent Rb atoms (Wyckoff positions: 4c and 8d), one independent P atom (Wyckoff position: 4c), and two independent S atoms (Wyckoff positions: 4c and 8d). The P<sup>5+</sup> cation is located in the center of its common tetrahedron, with P–S bond lengths ranging from 2.043 to 2.055 Å and the bond angles in the range of 108.82–111.48°. Ternary Rb<sub>3</sub>PS<sub>4</sub> belongs to the orthorhombic system [space group: *Pnma* (no. 62)] and the crystal structure consists of counterbalanced Rb<sup>+</sup> cations situated in between discrete tetrahedral [PS<sub>4</sub>] basic building units (BBUs) aligned parallel in opposing orientations (Fig. 2a). Unfortunately, Rb<sub>3</sub>PS<sub>4</sub> lacks NLO activity due to its CS crystal structure.

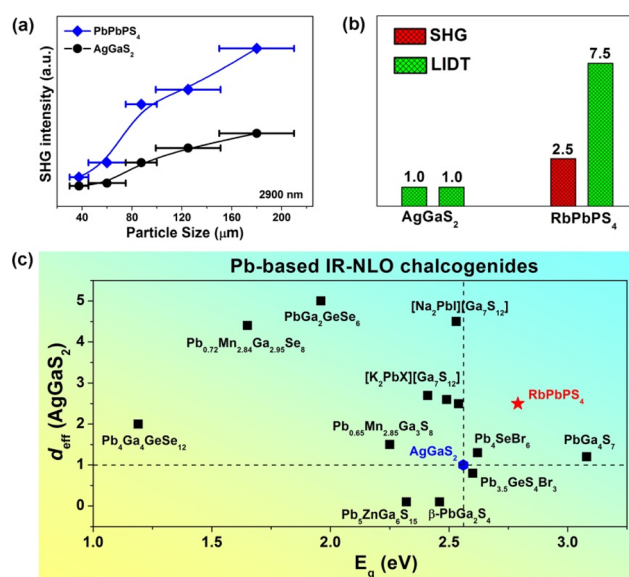
Quaternary RbPbPS<sub>4</sub> adopts the NCS orthorhombic space group *P2<sub>1</sub>2<sub>1</sub>2<sub>1</sub>* (no. 19, Table S1†), according to single-crystal XRD investigation. The cell lattice possesses dimensions of  $a = 6.3981(2)$  Å,  $b = 6.6888(2)$  Å,  $c = 17.2823(5)$  Å, and  $V = 739.61(4)$  Å<sup>3</sup>. These crystal parameters are in good agreement with the NCS phase that was previously published. The compound has a 2D layered structure with discrete counterbalanced Rb<sup>+</sup> cations inserted in the channels that are arranged in an “ABABAB” mode perpendicular to the *ab*-plane (Fig. 2b and c). With seven S atoms polyhedral coordinating each Pb atom in the structure, the highly distorted [PbS<sub>7</sub>] BBUs with Pb–S bond lengths of 2.916–3.281 Å are formed. As shown in Fig. 2d, adjacent [PbS<sub>7</sub>] BBUs are joined by apex-sharing S atoms to generate a 2D Pb–S layer. While the P–S bonds in RbPbPS<sub>4</sub> range in length from 2.031 to 2.069 Å and in bond angles from 106.56 to 111.62°, each P atom is comparable to that of Rb<sub>3</sub>PS<sub>4</sub> and is encircled by four S atoms, forming the deformed [PS<sub>4</sub>] tetrahedron (Table S2†). Subsequently, apex-sharing between these 2D Pb–S layers (Fig. 2d) and distinct [PS<sub>4</sub>] BBUs (Fig. 2e) progressively linked them, resulting in the formation of a 2D [PbPS<sub>4</sub>]<sup>−</sup> anionic layer (Fig. 2c).

Fig. 2 shows the CS-to-NCS structural evolution *via* partial SCALP cation substitution from ternary CS Rb<sub>3</sub>PS<sub>4</sub> to quaternary NCS RbPbPS<sub>4</sub>. From a structural perspective, the following

noteworthy modifications have been made following the partial replacement of Rb by SCALP Pb. First off, the initial highly symmetric structure is broken by the addition of SCALP [PbS<sub>7</sub>] BBUs and the reassembly of discrete [PS<sub>4</sub>] BBUs, which



**Fig. 3** (a) Group–subgroup relations between CS Rb<sub>3</sub>PS<sub>4</sub> [space group: *Pnma* (no. 62)] and NCS RbPbPS<sub>4</sub> [space group: *P2<sub>1</sub>2<sub>1</sub>2<sub>1</sub>* (no. 19)]; (b) crystal orbital Hamiltonian population (COHP) curves for the Pb–S bond length in RbPbPS<sub>4</sub> (the inset figure is the coordination geometry of Pb atom).



**Fig. 4** (a) SHG intensities vs. particle size at  $\lambda = 2900$  nm for PbPbPS<sub>4</sub> and AgGaS<sub>2</sub>; (b) the relative SHG and LIDT intensities of PbPbPS<sub>4</sub> and reference commercial material AgGaS<sub>2</sub> in the particle size of 150–210  $\mu\text{m}$ ; (c) comparison of  $d_{\text{eff}}$  (xAgGaS<sub>2</sub>) and  $E_g$  (eV) of reported Pb-based IR-NLO chalcogenides.



convert the 0D cluster structure into a 2D layered structure. Fig. 2f and g show the detailed symmetric operation modifications that occur after the substitution of SCALP  $\text{Pb}^{2+}$  cations, resulting in the removal of all center sites and the realization of the CS-to-NCS structural evolution. In particular, space group  $Pnma$  (no. 62) converts to  $P2_12_12_1$  (no. 19) from the Bärnighausen tree via a *translationengleiche* reduction in index 2's symmetry (Fig. 3a).<sup>22</sup> When Pb is substituted for Rb, the atomic positions (4c and 8d) in  $\text{Rb}_3\text{PS}_4$  become 4a in  $\text{RbPbPS}_4$  (see Table S3† for details). To put it briefly, the novel compound that was produced,  $\text{RbPbPS}_4$ , has good structural anisotropy, which helps to get a higher  $\Delta n$  for achieving PM feature. Secondly, the coordination number (CN) of the two crystallographically independent Rb atoms in  $\text{Rb}_3\text{PS}_4$  differ (CN = 8 for Rb1 and CN = 9 for Rb2), but are identical in  $\text{RbPbPS}_4$  (CN = 11) with Rb–S bond distances less than 4.4 Å (refer to Fig. S2 and S3 in ESI†). Finally, considering the flexible CN of  $\text{Pb}^{2+}$  cations, the integrated crystal orbital Hamilton population (ICOHP) curve was examined.<sup>23</sup> As depicted in Fig. 3b, it is evident that the short Pb–S bond lengths of 2.916–3.114 Å exhibit stronger bonding interactions compared

to the long Pb–S bond lengths (3.647–3.825 Å), while the Pb–S bond distance of 3.281 Å falls between them, representing a medium interaction (see Table S2† for details). Based on the above analysis, it is reasonable to infer that the Pb atom forms a  $[\text{PbS}_7]$  mono-capped triangular prism. Research on the distinct  $[\text{PbS}_7]$  coordination mode in NCS chalcogenides is notably lacking, and a seven-coordinated example of this has been reported in  $\text{Pb}_5\text{Ga}_6\text{ZnS}_{15}$ .<sup>8d</sup>  $\text{Pb}^{2+}$  cations in NCS chalcogenides are mostly five-coordinated (as in  $[\text{Na}_2\text{PbI}][\text{Ga}_7\text{S}_{12}]^{8f}$ ) or six-coordinated (as in  $\text{Pb}_4\text{Ga}_4\text{GeS}_{12}$ <sup>8a</sup> and  $\text{Pb}_{0.65}\text{Mn}_{2.85}\text{Ga}_3\text{S}_8$ <sup>8b</sup>), among other compounds that have been found.

Furthermore, through comparison with known ternary and quaternary chalcophosphates, it is determined that substituting SCALP Pb for partial alkali metal Rb is the most optimal and rational structural approach to accomplish the CS-to-NCS structural transformation of template structure  $\text{Rb}_3\text{PS}_4$ . Fig. S4† provides a detailed structural evolution. Roughly speaking, these replacements fall into three categories. In the first, three Rb atoms are completely substituted by one trivalent element or three monovalent elements in the absence of

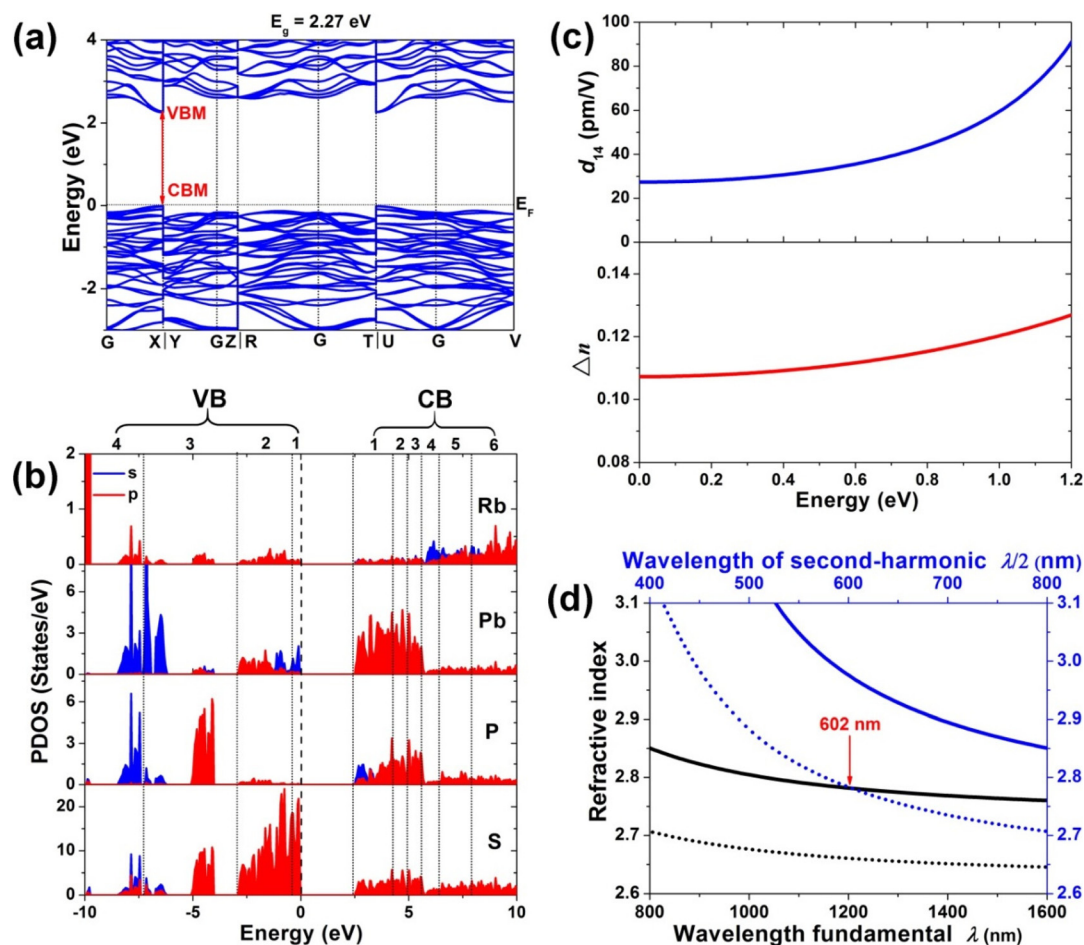


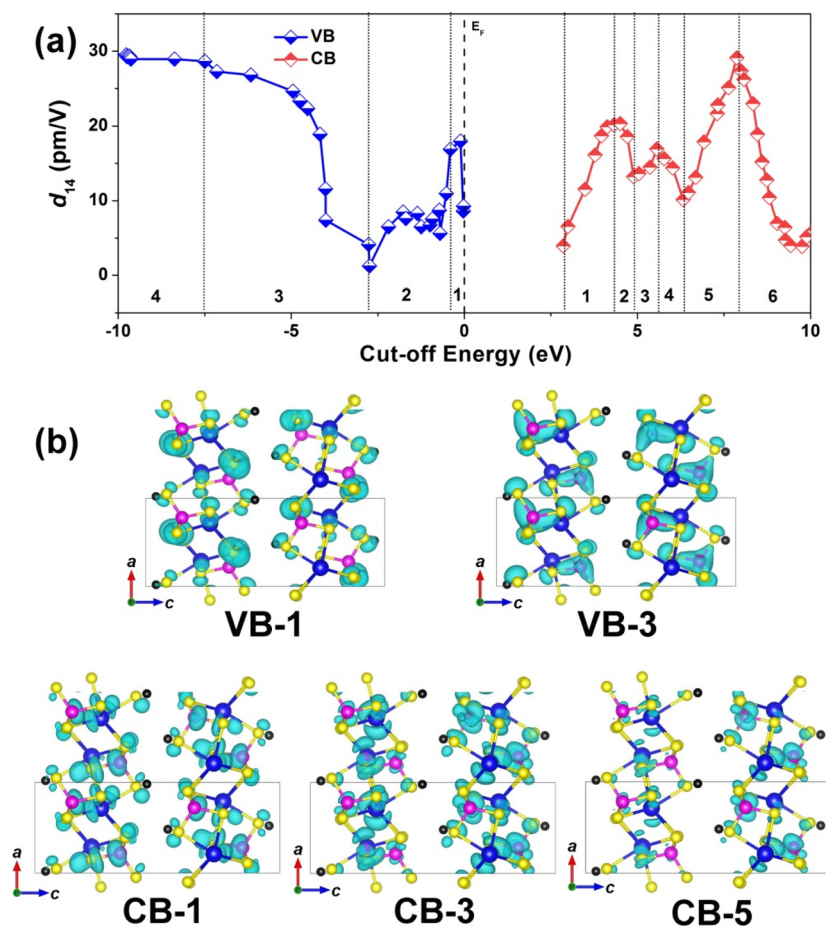
Fig. 5 Theoretical results of electronic structures and optical parameters of  $\text{PbPbPS}_4$ : (a) band structure; (b) partial density of states; (c) calculated nonzero independent SHG coefficient  $d_{14}$  ( $\text{pm V}^{-1}$ ) and calculated birefringence ( $\Delta n$ ); (d) calculated refractive index dispersion curves with the shortest type-I PM cut-off wavelength.



SCALP components. CS structures are displayed by the resultant compounds, including REPS<sub>4</sub> (space group: *I*<sub>4</sub>*1/acd*),<sup>24</sup> BPS<sub>4</sub> (space group: *Ibam*),<sup>25</sup> GaPS<sub>4</sub> (space group: *P*<sub>2</sub>*1/c*),<sup>26</sup> and Tl<sub>3</sub>PS<sub>4</sub> (space group: *Pnma*).<sup>27</sup> The second category entails complete substitution of SCALP elements, as seen in SbPS<sub>4</sub> (space group: *P* $\bar{1}$ )<sup>28</sup> and BiPS<sub>4</sub> (space group: *Ibca*),<sup>29</sup> which also belong to the CS structures. The third category involves partial substitution, where Rb is partially replaced by monovalent or divalent elements. The resulting compounds, such as Rb<sub>2</sub>AgPS<sub>4</sub> (space group: *P* $\bar{1}$ ),<sup>30</sup> RbAg<sub>5</sub>P<sub>2</sub>S<sub>8</sub> (space group: *Pbca*),<sup>31</sup> RbSrPS<sub>4</sub> (space group: *Pnma*),<sup>32</sup> RbBaPS<sub>4</sub> (space group: *Pnma*),<sup>33</sup> RbPdPS<sub>4</sub> (space group: *I4/mcm*),<sup>34</sup> and RbHgPS<sub>4</sub> (space group: *P*<sub>2</sub>*1/n*),<sup>35</sup> all adopt CS structures. Therefore, it is reasonable to replace partial Rb with SCALP elements to realize a structural transition from CS Rb<sub>3</sub>PS<sub>4</sub> to NCS RbPbPS<sub>4</sub>. Hence, employing established CS chalcophosphates as the parent structure and partially substituting them with SCALP-cation groups proves to be an effective chemical strategy for accomplishing the CS-to-NCS structural evolution.

As RbPbPS<sub>4</sub> belongs to the NCS space group *P*<sub>2</sub>*1**2**1**2**1* and possesses the NLO-active motifs [Pb<sub>7</sub>] and [PS<sub>4</sub>], a relatively

strong  $d_{\text{eff}}$  could be expected. Powder SHG testing for RbPbPS<sub>4</sub> was conducted using the modified Kurtz–Perry technology,<sup>35</sup> with irradiation from a 2900 nm laser and commercial material AgGaS<sub>2</sub> as a reference. As depicted in Fig. 4a, the positive correlation between the particle size and SHG intensity indicates that RbPbPS<sub>4</sub> exhibits PM behavior. The SHG intensity of RbPbPS<sub>4</sub> is approximately 2.5 times that of benchmark AgGaS<sub>2</sub> in a particle size range of 150–210  $\mu\text{m}$  (Fig. 4b). Based on  $d_{\text{eff}} = d_{\text{eff,R}} (I^2\omega/I_R^2\omega)^{1/2}$  ( $d_{\text{eff,R}} = 13.4 \text{ pm V}^{-1}$  for AgGaS<sub>2</sub>), the effective SHG coefficient  $d_{\text{eff}}$  of RbPbPS<sub>4</sub> at 2900 nm is 21.2  $\text{pm V}^{-1}$ . In addition, powder LIDT measurement was employed to preliminarily evaluate the LIDT value,<sup>36</sup> with the increased optical  $E_g$  suggesting that the title crystal would exhibit higher LIDT. As illustrated in Fig. 4b, the LIDT of RbPbPS<sub>4</sub> (10.88  $\text{MW cm}^{-2}$ ) is estimated to be 7.5 times that of AgGaS<sub>2</sub> (1.45  $\text{MW cm}^{-2}$ ) under the same testing conditions. Compared with other reported Pb-based IR-NLO materials (Fig. 4c and Table S4†), RbPbPS<sub>4</sub> demonstrates a favorable balance between strong  $d_{\text{eff}}$  and large  $E_g$ . Notably, RbPbPS<sub>4</sub> represents the first quaternary Pb-based chalcogenide to overcome the incompatibility between a wide  $E_g$  (>2.56 eV, the  $E_g$  of AgGaS<sub>2</sub>) and a



**Fig. 6** Theoretical analysis of the intrinsic mechanism of SHG source for PbPbPS<sub>4</sub>: (a) cut-off energy (eV) dependence of the static  $d_{14}$  ( $\text{pm V}^{-1}$ ); (b) distribution of the partial charge density maps with major contributions in the VB-1, VB-3, CB-1, CB-3 and CB-5 regions. Black atoms: Rb; blue atoms: Pb; pink atoms: P; yellow atoms: S.



sufficient  $d_{\text{eff}}$  ( $>1.0 \times \text{AgGaS}_2$ ). This balance IR-NLO performance can be compared to the recently reported quaternary NCS chalcogenides, such as  $\alpha\text{-Li}_2\text{ZnGeS}_4$ ,<sup>37</sup>  $\text{Li}_4\text{CdSn}_2\text{S}_7$ ,<sup>38</sup>  $\text{NaMg}_3\text{Ga}_3\text{S}_8$ ,<sup>39</sup> and  $(\text{CuI})_3\text{P}_4\text{S}_4$ .<sup>40</sup>

To gain further insights into the underlying structure–property relationship of the title compound, systematic theoretical calculations were conducted, encompassing band structure, densities of states (DOSs), and linear optical and NLO parameters, based on DFT. The calculated electronic band structure reveals a direct  $E_g$  of 2.27 eV for  $\text{RbPbPS}_4$ , as the valence band maximum (VBM) and conduction band minimum (CBM) coincide at the same high-symmetry  $k$ -points (Fig. 5a). The smaller calculated  $E_g$  can be attributed to underestimation by the DFT calculation.<sup>41</sup> The partial DOSs of  $\text{RbPbPS}_4$  are depicted in Fig. 5b, indicating that the tops of the VBs are predominantly composed of S-3p states, with a minor contribution from Pb-5s and P-3p states, while the bottoms of the CBs primarily consist of S-3p, Pb-5p, P-3s/3p, and Rb-5p states. Furthermore, the NLO coefficients of  $\text{RbPbPS}_4$  can be calculated according to the electronic structure. In the light of Kleinman symmetry,<sup>42</sup>  $\text{RbPbPS}_4$  exhibits only one nonzero independent SHG coefficient,  $d_{14} = 31.8 \text{ pm V}^{-1}$  at 2900 nm (*ca.* 0.43 eV) (Fig. 5c). Furthermore, the calculated  $d_{\text{eff}}$  of  $\text{RbPbPS}_4$  is  $26.88 \text{ pm V}^{-1}$ , under 2900 nm irradiation,<sup>35</sup> which essentially coincides with the experimental findings. Additionally, the calculated  $\Delta n$  value of  $\text{RbPbPS}_4$  is 0.109 at 2900 nm, significantly surpassing that of  $\text{AgGaS}_2$  ( $\Delta n \sim 0.04$ ).<sup>43</sup> This suggests that  $\text{RbPbPS}_4$  may be well-suited to achieve the PM condition for the SHG process. Furthermore, the line refractive dispersion diagrams indicate that the shortest type-I phase-matched output wavelength is 602 nm (Fig. 5d).<sup>44</sup>

To visually illustrate the contribution of the constituent BBUs to the SHG effect, the cutoff energy dependence of the static  $d_{14}$  for  $\text{RbPbPS}_4$  is calculated using a length-gauge formalism method.<sup>45</sup> As depicted in Fig. 6a, the  $d_{14}$  values exhibit an upward trend in the VB-1, VB-3, CB-1, CB-3, and CB-5 intervals. This illustrates that the orbitals in these regions have a significant influence on the overall NLO response.<sup>46</sup> Moreover, by integrating the partial DOSs (Fig. 5b) with the relevant partial charge density maps (Fig. 6b), it is evident that the enhancement of the  $d_{\text{eff}}$  in  $\text{RbPbPS}_4$  primarily stems from the strong hybridization of electron states at the top of the VBs and the substantial distortion of  $[\text{PbS}_7]$  and  $[\text{PS}_4]$  groups, indicative of the 2D  $[\text{PbPS}_4]^-$  alternating arrangement layer.

## Conclusions

In summary, building upon the parent ternary CS compound  $\text{Rb}_3\text{PS}_4$ , we implemented a strategy involving the partial substitution of Rb with SCALP Pb, resulting in the creation of a new quaternary NCS chalcophosphate,  $\text{RbPbPS}_4$ . This substitution also triggered a structural transformation from 0D clusters to 2D layers. As anticipated, experimental findings highlight  $\text{RbPbPS}_4$  as a promising candidate for IR-NLO applications, boasting a large  $d_{\text{eff}}$  ( $2.5 \times \text{AgGaS}_2$  at 2900 nm), a broad trans-

mittance cutoff window (0.38–18.1  $\mu\text{m}$ ), and a significant  $E_g$  (2.75 eV) conducive to a high LIDT ( $7.5 \times \text{AgGaS}_2$  at 1064 nm). Detailed structure–property analyses elucidate that the strong calculated  $d_{\text{eff}}$  ( $26.88 \text{ pm V}^{-1}$  at 2900 nm) and large calculated birefringence (0.109@2900 nm) in  $\text{RbPbPS}_4$  primarily stem from the cooperative effects of  $[\text{PbS}_7]$  and  $[\text{PS}_4]$  NLO-active motifs. These findings underscore the efficacy of the lone-pair-cation substitution strategy in achieving both structural transformation and effectively balancing strong  $d_{\text{eff}}$  with a large  $E_g$  in SCALP-based chalcogenides.

## Author contributions

A-Yang Wang: investigation, formal analysis, writing – original draft. Sheng-Hua Zhou: investigation, methodology, validation. Mao-Yin Ran: investigation, formal analysis, validation. Bingxuan Li: formal analysis, validation. Xin-Tao Wu: conceptualization, writing – review & editing. Hua Lin: supervision, conceptualization, writing – review & editing. Qi-Long Zhu: supervision, writing – review & editing.

## Conflicts of interest

There are no conflicts to declare.

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## References

- (a) F. J. Duarte, *Tunable Laser Applications*, CRC Press, Boca Raton, FL, 2008, ch. 2, 9 and 12; (b) V. Petrov, Frequency down-conversion of solid-state laser sources to the mid-infrared spectral range using non-oxide nonlinear crystals, *Prog. Quantum Electron.*, 2015, **44**, 1–106; (c) X.-T. Wu and L. Chen, Structure-Property Relationships in Nonlinear Optical Crystals II The IR Region, *Structure Bonding*, 2012, **145**, 1–42; (d) N. L. B. Sayson, T. Bi, V. Ng, H. Pham, L. S. Trainor, H. G. L. Schwefel, S. Coen, M. Erkintalo and S. G. Murdoch, Octave-spanning tunable parametric oscillation in crystalline Kerr microresonators, *Nat. Photonics*, 2019, **13**, 701–706; (e) J.-X. Zhang, P. Feng, M.-Y. Ran, X.-T. Wu, H. Lin and Q.-L. Zhu, Ga-based IR nonlinear optical materials: Synthesis, structures, and properties, *Coord. Chem. Rev.*, 2024, **502**, 215617.

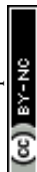


- 2 (a) L. Kang, M. Zhou, J. Yao, Z. Lin, Y. Wu and C. Chen, Metal Thiophosphates with Good Mid-infrared Nonlinear Optical Performances: A First-Principles Prediction and Analysis, *J. Am. Chem. Soc.*, 2015, **137**, 13049–13059; (b) P. S. Halasyamani and W. Zhang, Viewpoint: Inorganic Materials for UV and Deep-UV Nonlinear-Optical Applications, *Inorg. Chem.*, 2017, **56**, 12077–12085; (c) Y. Pan, S.-P. Guo, B.-W. Liu, H.-G. Xue and G.-C. Guo, Second-order nonlinear optical crystals with mixed anions, *Coord. Chem. Rev.*, 2018, **374**, 464–496; (d) M. Mutailipu, K. R. Poeppelmeier and S. Pan, Borates: A Rich Source for Optical Materials, *Chem. Rev.*, 2021, **121**, 1130–1202; (e) H. Chen, M.-Y. Ran, W.-B. Wei, X.-T. Wu, H. Lin and Q.-L. Zhu, A comprehensive review on metal chalcogenides with three-dimensional frameworks for infrared nonlinear optical applications, *Coord. Chem. Rev.*, 2022, **470**, 214706.
- 3 (a) A. Harasaki and K. J. Kato, New Data on the Nonlinear Optical Constant, Phase-Matching, and Optical Damage of AgGaS<sub>2</sub>, *Appl. Phys.*, 1997, **36**, 700–703; (b) G. C. Catella, L. R. Shiozawa, J. R. Hietanen, R. C. Eckardt, R. K. Route, R. S. Feigelson, D. G. Cooper and C. L. Marquardt, Mid-IR absorption in AgGaSe<sub>2</sub> optical parametric oscillator crystals, *Appl. Opt.*, 1993, **32**, 3948–3951.
- 4 G. D. Boyd, E. Buehler and F. G. Storz, Linear and nonlinear optical properties of ZnGeP<sub>2</sub> and CdSe, *Appl. Phys. Lett.*, 1971, **18**, 301–304.
- 5 (a) K. Wu and S. Pan, A review on structure-performance relationship toward the optimal design of infrared nonlinear optical materials with balanced performances, *Coord. Chem. Rev.*, 2018, **377**, 191–208; (b) L. Kang, F. Liang, X. Jiang, Z. Lin and C. Chen, First-Principles Design and Simulations Promote the Development of Nonlinear Optical Crystals, *Acc. Chem. Res.*, 2020, **53**, 209–217; (c) W. Wang, D. Mei, F. Liang, J. Zhao, Y. Wu and Z. Lin, Inherent laws between tetrahedral arrangement pattern and optical performance in tetrahedron-based mid-infrared nonlinear optical materials, *Coord. Chem. Rev.*, 2020, **421**, 213444; (d) H.-D. Yang, M.-Y. Ran, W.-B. Wei, X.-T. Wu, H. Lin and Q.-L. Zhu, Recent advances in IR nonlinear optical chalcogenides with well-balanced comprehensive performance, *Mater. Today Phys.*, 2023, **35**, 101127; (e) L. Luo, L. Wang, J. Chen, J. Zhou, Z. Yang, S. Pan and J. Li, AIB<sub>3</sub>IIC<sub>3</sub>IIIQ<sub>8</sub>VI: A New Family for the Design of Infrared Nonlinear Optical Materials by Coupling Octahedra and Tetrahedra Units, *J. Am. Chem. Soc.*, 2022, **144**, 21916–21925; (f) M.-Y. Ran, S.-H. Zhou, W.-B. Wei, B.-X. Li, X.-T. Wu, H. Lin and Q.-L. Zhu, Breaking through the Trade-Off between Wide Band Gap and Large SHG Coefficient in Mercury-based Chalcogenides for IR Nonlinear Optical Application, *Small*, 2024, **20**, 2304563; (g) W. Zhou and S.-P. Guo, Rational Design of Novel Promising Infrared Nonlinear Optical Materials: Structural Chemistry and Balanced Performances, *Acc. Chem. Res.*, 2024, **57**, 648–660.
- 6 (a) P. S. Halasyamani and K. R. Poeppelmeier, Noncentrosymmetric Oxides, *Chem. Mater.*, 1998, **10**, 2753–2769; (b) K. M. Ok, Toward the Rational Design of Novel Noncentrosymmetric Materials: Factors Influencing the Framework Structures, *Acc. Chem. Res.*, 2016, **49**, 2774–2785; (c) Y. Hu, C. Wu, X. Jiang, Z. Wang, Z. Huang, Z. Lin, X. Long, M. G. Humphrey and C. Zhang, Giant Second-Harmonic Generation Response and Large Band Gap in the Partially Fluorinated Mid-Infrared Oxide RbTeMo<sub>2</sub>O<sub>8</sub>F, *J. Am. Chem. Soc.*, 2021, **143**, 12455–12459; (d) H. Chen, W.-B. Wei, H. Lin and X.-T. Wu, Transition-metal-based chalcogenides: A rich source of infrared nonlinear optical materials, *Coord. Chem. Rev.*, 2021, **448**, 214154; (e) P.-F. Li, J.-G. Mao and F. Kong, A survey of stereoactive oxysalts for linear and nonlinear optical applications, *Mater. Today Phys.*, 2023, **37**, 101197.
- 7 (a) M. Yan, H.-G. Xue and S.-P. Guo, Recent Achievements in Lone-Pair Cation-Based Infrared Second-Order Nonlinear Optical Materials, *Cryst. Growth Des.*, 2021, **21**, 698–720; (b) T. K. Bera, J.-H. Song, A. J. Freeman, J. I. Jang, J. B. Ketterson and M. G. Kanatzidis, Soluble direct-band-gap semiconductors LiAsS<sub>2</sub> and NaAsS<sub>2</sub>: Large electronic structure effects from weak As center dot center dot center dot S interactions and strong nonlinear optical response, *Angew. Chem., Int. Ed.*, 2008, **47**, 7828–7832; (c) F. Xu, X. Xu, B. Li, G. Zhang, C. Zheng, J. Chen and N. Ye, Hg<sub>3</sub>AsS<sub>4</sub>X (X = Cl and Br): two Hg-based chalcogenides as long-wave infrared nonlinear optical crystals with superior comprehensive performances, *Inorg. Chem. Front.*, 2024, **11**, 2105–2115; (d) H. Lin, Y. Y. Li, M. Y. Li, Z. J. Ma, L. M. Wu, X. T. Wu and Q. L. Zhu, Centric-to-acentric structure transformation induced by a stereochemically active lone pair: a new insight for design of IR nonlinear optical materials, *J. Mater. Chem. C*, 2019, **7**, 4638–4643; (e) Y. Xiao, M. M. Chen, Y. Y. Shen, P. F. Liu, H. Lin and Y. Liu, A<sub>3</sub>Mn<sub>2</sub>Sb<sub>3</sub>S<sub>8</sub> (A = K, Rb): A new type of multifunctional infrared nonlinear optical materials based on unique three-dimensional open frameworks, *Inorg. Chem. Front.*, 2021, **8**, 2835–2843; (f) H.-J. Zhao, H.-D. Yang, P.-F. Liu and H. Lin, From Cc to P6<sub>3</sub>mc: Structural Variation in La<sub>3</sub>S<sub>2</sub>Cl<sub>2</sub>[SbS<sub>3</sub>] and La<sub>3</sub>O<sub>2</sub>OSCl<sub>2</sub>[SbS<sub>3</sub>] Induced by the Isovalent Anion Substitution, *Cryst. Growth Des.*, 2022, **22**, 1437–1444; (g) Y. Zhou, L.-T. Jiang, X.-M. Jiang, B.-W. Liu and G.-C. Guo, Mixed-anion square-pyramid [SbS<sub>3</sub>I<sub>2</sub>] units causing strong second-harmonic generation intensity and large birefringence, *Chin. Chem. Lett.*, 2024, 109740; (h) M. Y. Li, B. X. Li, H. Lin, Z. J. Ma, L. M. Wu, X. T. Wu and Q. L. Zhu, Sn<sub>2</sub>Ga<sub>2</sub>S<sub>5</sub>: A Polar Semiconductor with Exceptional Infrared Nonlinear Optical Properties Originating from the Combined Effect of Mixed Asymmetric Building Motifs, *Chem. Mater.*, 2019, **31**, 6268–6275; (i) C. Zhao, B. Zhang, X. Tian, G. Zhou, J. Xu and K. Wu, Na<sub>6</sub>Sn<sub>3</sub>P<sub>4</sub>S<sub>16</sub>: Sn(II)-chelated PS<sub>4</sub> groups inspired an ultra-strong SHG response, *Inorg. Chem. Front.*, 2023, **10**, 5726–5733; (j) X. Chen, Q. Jing and K. M. Ok, Pb<sub>18</sub>O<sub>8</sub>Cl<sub>15</sub>I<sub>5</sub>: A Polar Lead Mixed Oxyhalide with Unprecedented Architecture and Excellent Infrared Nonlinear Optical Properties, *Angew. Chem., Int. Ed.*, 2020, **59**, 20323–20327.





- 8 (a) Y. K. Chen, M. C. Chen, L. J. Zhou, L. Chen and L. M. Wu, Syntheses, Structures, and Nonlinear Optical Properties of Quaternary Chalcogenides:  $\text{Pb}_4\text{Ga}_4\text{GeQ}_{12}$  (Q = S, Se), *Inorg. Chem.*, 2013, **52**, 8334–8341; (b) M. Zhou, X. Jiang, Y. Guo, Z. Lin, J. Yao and Y. Wu,  $\text{Pb}_{0.65}\text{Mn}_{2.85}\text{Ga}_3\text{S}_8$  and  $\text{Pb}_{0.72}\text{Mn}_{2.84}\text{Ga}_{2.95}\text{Se}_8$ : Two Quaternary Metal Chalcogenides with Open-Tunnel-Framework Structures Displaying Intense Second Harmonic Generation Responses and Interesting Magnetic Properties, *Inorg. Chem.*, 2017, **56**, 8454–8461; (c) Z. Z. Luo, C. S. Lin, H. H. Cui, W. L. Zhang, H. Zhang, H. Chen, Z. Z. He and W. D. Cheng,  $\text{PbGa}_2\text{MSe}_6$  (M = Si, Ge): Two Exceptional Infrared Nonlinear Optical Crystals, *Chem. Mater.*, 2015, **27**, 914–922; (d) R. H. Duan, J. S. Yu, H. Lin, Y. J. Zheng, H. J. Zhao, S. X. Huang-Fu, M. A. Khan, L. Chen and L. M. Wu,  $\text{Pb}_5\text{Ga}_6\text{ZnS}_{15}$ : a noncentrosymmetric framework with chains of  $\text{T}_2$ -supertetrahedra, *Dalton Trans.*, 2016, **45**, 12288–12291; (e) W. F. Chen, B. W. Liu, X. M. Jiang and G. C. Guo, Infrared nonlinear optical performances of a new sulfide  $\beta\text{-PbGa}_2\text{S}_4$ , *J. Alloys Compd.*, 2022, **905**, 164090; (f) Z. X. Wu, W. F. Chen, X. M. Jiang, B. W. Liu and G. C. Guo,  $[\text{Na}_2\text{PbI}][\text{Ga}_7\text{S}_{12}]$ : Combining Diamond-Like Anionic Framework with Polycationic Chain toward Achieving Remarkable Nonlinear Optical Response, *Chem. Mater.*, 2024, **36**, 3444–3451; (g) W. F. Chen, B. W. Liu, S. M. Pei, X. M. Jiang and G. C. Guo,  $[\text{K}_2\text{PbX}][\text{Ga}_7\text{S}_{12}]$  (X = Cl, Br, I): The First Lead-Containing Cationic Moieties with Ultrahigh Second-Harmonic Generation and Band Gaps Exceeding the Criterion of 2.33 eV, *Adv. Sci.*, 2023, **10**, 2207630; (h) J. Zhou, H. Wang, J. Liu, X. Su, Y. Chu, J. Qu and X. Jiang,  $\text{Pb}_{3.5}\text{GeS}_4\text{Br}_3$ : The first phase-matching thiogermanate halide infrared nonlinear optical material, *Inorg. Chem. Front.*, 2024, **11**, 2681–2689; (i) J. Wang, H. Wu, H. Yu, Z. Hu, J. Wang and Y. Wu,  $\text{Pb}_4\text{SeBr}_6$ : A Congruently Melting Mid-Infrared Nonlinear Optical Material with Excellent Comprehensive Performance, *Adv. Opt. Mater.*, 2022, **10**, 2102673; (j) X. Li, L. Kang, C. Li, Z. Lin, J. Yao and Y. Wu,  $\text{PbGa}_4\text{S}_7$ : a wide-gap nonlinear optical material, *J. Mater. Chem. C*, 2015, **3**, 3060–3067.
- 9 J. Chen, Q. Wu, H. Tian, X. Jiang, F. Xu, X. Zhao, Z. Lin, M. Luo and N. Ye, Uncovering a Vital Band Gap Mechanism of Pnictides, *Adv. Sci.*, 2022, **9**, 2105787.
- 10 (a) H. Lin, W. B. Wei, H. Chen, X. T. Wu and Q. L. Zhu, Rational design of infrared nonlinear optical chalcogenides by chemical substitution, *Coord. Chem. Rev.*, 2020, **406**, 213150; (b) M.-Y. Ran, A. Y. Wang, W. B. Wei, X.-T. Wu, H. Lin and Q.-L. Zhu, Recent progress in the design of IR nonlinear optical materials by partial chemical substitution: Structural evolution and performance optimization, *Coord. Chem. Rev.*, 2023, **481**, 215059.
- 11 M.-M. Chen, Z. Ma, B.-X. Li, W.-B. Wei, X.-T. Wu, H. Lin and Q.-L. Zhu,  $\text{M}_2\text{As}_2\text{Q}_5$  (M = Ba, Pb Q = S, Se): A source of infrared nonlinear optical materials with excellent overall performance activated by multiple discrete arsenate anions, *J. Mater. Chem. C*, 2021, **9**, 1156–1163.
- 12 C. Liu, S.-H. Zhou, Y. Xiao, C. Zhang, H. Lin and Y. Liu, Aliovalent-cation-substitution-induced structure transformation: a new path toward high-performance IR nonlinear optical materials, *J. Mater. Chem. C*, 2021, **9**, 15407–15414.
- 13 M. M. Chen, S. H. Zhou, W. B. Wei, B. X. Li, M. Y. Ran, X. T. Wu, H. Lin and Q. L. Zhu,  $\text{RbBiP}_2\text{S}_6$ : A Promising IR Nonlinear Optical Material with a Giant Second-Harmonic Generation Response Designed by Aliovalent Substitution, *ACS Mater. Lett.*, 2022, **4**, 1264–1269.
- 14 V. Nguyen, B. Ji, K. Wu, B. Zhang and J. Wang, Unprecedented mid-infrared nonlinear optical materials achieved by crystal structure engineering, a case study of  $(\text{KX})\text{P}_2\text{S}_6$  (X = Sb, Bi, Ba), *Chem. Sci.*, 2022, **13**, 2640–2648.
- 15 X. H. Li, Z. H. Shi, M. Yang, W. Liu and S. P. Guo,  $\text{Sn}_7\text{Br}_{10}\text{S}_2$ : The First Ternary Halogen-Rich Chalcohalide Exhibiting a Chiral Structure and Pronounced Nonlinear Optical Properties, *Angew. Chem., Int. Ed.*, 2022, **61**, e202115871.
- 16 L. T. Menezes, A. Assoud, W. Zhang, P. S. Halasyamani and H. Kleinke, Effect of Pb Substitution in  $\text{Sr}_{(2-x)}\text{Pb}_x\text{GeSe}_4$  on Crystal Structures and Nonlinear Optical Properties Predicted by DFT Calculations, *Inorg. Chem.*, 2020, **59**, 15028–15035.
- 17 J. Wang, H. Wu, H. Yu, Z. Hu, J. Wang and Y. Wu,  $\text{Pb}_4\text{SeBr}_6$ : A Congruently Melting Mid-Infrared Nonlinear Optical Material with Excellent Comprehensive Performance, *Adv. Opt. Mater.*, 2022, **10**, 2102673.
- 18 L.-B. Wu and F.-Q. Huang, Crystal structure of trirubidium tetrathiophosphate,  $\text{Rb}_3\text{PS}_4$ , *Z. Kristallogr. – New Cryst. Struct.*, 2005, **220**, 122–122.
- 19 (a) J. Yao and J. A. Ibers,  $\text{RbPbPS}_4$ , *Acta Crystallogr., Sect. E: Struct. Rep. Online*, 2004, **60**, i108–i110; (b) I. Belkhal, M. ElAzhari, Y. D. Wu, W. Bensch and W. Depmeier, Phase transition of rubidium lead tetrathiophosphate  $\text{RbPbPS}_4$ , *Z. Anorg. Allg. Chem.*, 2009, **635**, 1600–1603.
- 20 Y. Z. Huang, L. Chen and L. M. Wu, Submicrosized Rods, Cables, and Tubes of ZnE (E = S, Se, Te): Exterior-Interior Boron-Chalcogen Conversions and Optical Properties, *Inorg. Chem.*, 2008, **47**, 10723–10728.
- 21 P. Kubelka and F. Munk, Reflection characteristics of paints, *Z. Tech. Phys.*, 1931, **12**, 593–601.
- 22 U. Englert, *Symmetry Relationships between Crystal Structures*, Oxford University Press: Oxford, UK, 2013.
- 23 R. Dronskowski and P. E. Bloechl, Crystal orbital Hamilton populations (COHP): energy-resolved visualization of chemical bonding in solids based on density-functional calculations, *J. Phys. Chem.*, 1993, **97**, 8617–8624.
- 24 T. Komm, D. Gudat and T. Schleid, Die Lanthanid (III)-ortho-Thiophosphate(V) vom Typ  $\text{M}[\text{PS}_4]$  (M = La–Nd, Sm, Gd–Er): Synthese, Kristallstruktur und  $^{31}\text{P}$ -NMR-Untersuchungen, *Z. Naturforsch.*, 2006, **61b**, 766–774.
- 25 F. Pielhofer, L. M. Schoop, A. Kuhn, R. Eger, J. Nuss, H. Nuss and B. V. Lotsch, New Light on an Old Story: The Crystal Structure of Boron Tetrathiophosphate Revisited, *Z. Anorg. Allg. Chem.*, 2019, **645**, 267–271.
- 26 P. Buck and C. D. Carpentier, The Crystal Structure of Gallium Thiophosphate,  $\text{GaPS}_4$ , *Acta Crystallogr., Sect. B: Struct. Crystallogr. Cryst. Chem.*, 1973, **29**, 1864–1868.



- 27 P. Toffoli, P. Khodadad and N. Rodier, Structure cristalline du tetrathiomonophosphate (V) de thallium(I)  $Tl_3PS_4$ , *Bull. Soc. Chim. Fr.*, 1981, 429–432.
- 28 C. D. Malliakas and M. G. Kanatzidis, Inorganic Single Wall Nanotubes of  $SbPS_{4-x}Se_x$  ( $0 \leq x \leq 3$ ) with Tunable Band Gap, *J. Am. Chem. Soc.*, 2006, **128**, 6538–6539.
- 29 D. Tiwari, D. Alibhai, D. Cherns and D. J. Fermin, Crystal and Electronic Structure of Bismuth Thiophosphate,  $BiPS_4$ : An Earth-Abundant Solar Absorber, *Chem. Mater.*, 2020, **32**, 1235–1242.
- 30 F. Alahmari, B. Davaasuren, J. Khanderi and A. Rothenberger, Synthesis and Characterization of the Rubidium Thiophosphate  $Rb_6(PS_5)(P_2S_{10})$  and the Rubidium Silver Thiophosphates  $Rb_2AgPS_4$ ,  $RbAg_5(PS_4)_2$  and  $Rb_3Ag_9(PS_4)_4$ , *Z. Anorg. Allg. Chem.*, 2016, **642**, 361–367.
- 31 A. Mesbah, J. Prakash, D. Rocca, S. Lebègue, J. C. Beard, B. A. Lewis and J. A. Ibers, Syntheses, crystal structure, and electronic properties of the five  $ABaMQ_4$  compounds  $RbBaPS_4$ ,  $CsBaPS_4$ ,  $CsBaVS_4$ ,  $RbBaVSe_4$ , and  $CsBaVSe_4$ , *J. Solid State Chem.*, 2016, **233**, 217–220.
- 32 Y. Huang, J. Huang and Y. Zhang, Wide band gap thiophosphates  $ASrPS_4$  ( $A = Li, Na, K, Rb, Cs$ ): cation size effect induced successive structural transformation, *Dalton Trans.*, 2022, **51**, 15067–15073.
- 33 S. Coste, J. Hanko, M. Bujoli-Doeuff, G. Louarn, M. Evain, R. Brec, B. Alonso, S. Jobic and M. G. Kanatzidis,  $NaPdPS_4$  and  $RbPdPS_4$ : systems with infinite straight  $\frac{1}{\infty} [PdPS_4]^-$  chains soluble in polar solvents and the structure of cubic  $RbPdPS_4\{Rb_{0.33}P_{0.4}S_{2.23}O_x\}$ , *J. Solid State Chem.*, 2003, **175**, 133–145.
- 34 W. Xing, C. Tang, P. Gong, J. Wu, Z. Lin, J. Yao, W. Yin and B. Kang, Investigation into Structural Variation from 3D to 1D and Strong Second Harmonic Generation of the  $AH_2PS_4$  ( $A^+ = Na^+, K^+, Rb^+, Cs^+$ ) Family, *Inorg. Chem.*, 2021, **60**, 18370–18378.
- 35 S. K. Kurtz and T. T. Perry, A powder technique for the evaluation of nonlinear optical materials, *J. Appl. Phys.*, 1968, **39**, 3798–3813.
- 36 M. J. Zhang, X. M. Jiang, L. J. Zhou and G. C. Guo, Two phases of  $Ga_2S_3$ : promising infrared second-order nonlinear optical materials with very high laser induced damage thresholds, *J. Mater. Chem. C*, 2013, **1**, 4754–4760.
- 37 J.-H. Zhang, D. J. Clark, J. A. Brant, K. A. Rosmus, P. Grima, J. W. Lekse, J. I. Jang and J. A. Aitken,  $\alpha$ - $Li_2ZnGeS_4$ : A Wide-Bandgap Diamond-like Semiconductor with Excellent Balance between Laser-Induced Damage Threshold and Second Harmonic Generation Response, *Chem. Mater.*, 2020, **32**, 8947–8955.
- 38 J.-H. Zhang, S. S. Stoyko, A. J. Craig, P. Grima, J. W. Kotchey, J. I. Jang and J. A. Aitken, Phase Matching, Strong Frequency Doubling, and Outstanding Laser-Induced Damage Threshold in the Biaxial, Quaternary Diamond-like Semiconductor  $Li_4CdSn_2S_7$ , *Chem. Mater.*, 2020, **32**, 10045–10054.
- 39 L. Luo, L. Wang, J. Chen, J. Zhou, Z. Yang, S. Pan and J. Li,  $A^I B^II_3 C^III_3 Q^VI_8$ : A New Family for the Design of Infrared Nonlinear Optical Materials by Coupling Octahedra and Tetrahedra Units, *J. Am. Chem. Soc.*, 2022, **144**, 21916–21925.
- 40 S. Yang, C. Lin, H. Fan, K. Chen, G. Zhang, N. Ye and M. Luo, Polar Phosphorus Chalcogenide Cage Molecules: Enhancement of Nonlinear Optical Properties in Adducts, *Angew. Chem., Int. Ed.*, 2023, **62**, e202218272.
- 41 K. Burke, Perspective on density functional theory, *J. Chem. Phys.*, 2012, **136**, 150901.
- 42 D. A. Kleinman, Nonlinear Dielectric Polarization in Optical Media, *Phys. Rev.*, 1962, **126**, 1977–1979.
- 43 (a) M. Y. Li, Z. J. Ma, B. X. Li, X. T. Wu, H. Lin and Q. L. Zhu,  $HgCuPS_4$ : An Exceptional Infrared Nonlinear Optical Material with Defect Diamond-like Structure, *Chem. Mater.*, 2020, **32**, 4331–4339; (b) M. Y. Ran, Z. J. Ma, H. Chen, B. X. Li, X. T. Wu, H. Lin and Q. L. Zhu, Partial Isovalent Anion Substitution to Access Remarkable Second-Harmonic Generation Response: A Generic and Effective Strategy for Design of Infrared Nonlinear Optical Materials, *Chem. Mater.*, 2020, **32**, 5890–5896; (c) M. M. Chen, S. H. Zhou, W. B. Wei, X. T. Wu, H. Lin and Q. L. Zhu, Phase Matchability Transformation in the Infrared Nonlinear Optical Materials with Diamond-Like Frameworks, *Adv. Opt. Mater.*, 2022, **10**, 2102123.
- 44 (a) M. Y. Ran, S. H. Zhou, B. X. Li, W. B. Wei, X. T. Wu, H. Lin and Q. L. Zhu, Enhanced Second-Harmonic-Generation Efficiency and Birefringence in Melillite Oxychalcogenides  $Sr_2MGe_2OS_6$  ( $M = Mn, Zn, \text{ and } Cd$ ), *Chem. Mater.*, 2022, **34**, 3853–3861; (b) A.-Y. Wang, S. H. Zhou, M. Y. Ran, X. T. Wu, H. Lin and Q. L. Zhu, Regulating the key performance parameters for Hg-based IR NLO chalcogenides via bandgap engineering strategy, *Chin. Chem. Lett.*, 2024, **35**, 109377; (c) M. Y. Ran, S. H. Zhou, X. T. Wu, H. Lin and Q. L. Zhu, The first Hg-based oxychalcogenide  $Sr_2HgGe_2OS_6$ : Achieving balanced IR nonlinear optical properties through synergistic cation and anion substitution, *Mater. Today Phys.*, 2024, **44**, 101442.
- 45 (a) C. Aversa and J. E. Sipe, Nonlinear optical susceptibilities of semiconductors: Results with a length-gauge analysis, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1995, **52**, 14636–14645; (b) S. N. Rashkeev, W. R. L. Lambrecht and B. Segall, Efficient ab initio method for the calculation of frequency-dependent second-order optical response in semiconductors, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1998, **57**, 3905–3919.
- 46 (a) H. Chen, Y.-Y. Li, B.-X. Li, P.-F. Liu, H. Lin, Q.-L. Zhu and X.-T. Wu, Salt-Inclusion Chalcogenide  $[Ba_4Cl_2][ZnGa_4S_{10}]$ : Rational Design of an IR Nonlinear Optical Material with Superior Comprehensive Performance Derived from  $AgGaS_2$ , *Chem. Mater.*, 2020, **32**, 8012–8019; (b) H.-D. Yang, M.-Y. Ran, S.-H. Zhou, B.-X. Li, X.-T. Wu, H. Lin and Q.-L. Zhu, Rational Design via Dual-Site Aliovalent Substitution Leads to an Outstanding IR Nonlinear Optical Material with Well-Balanced Comprehensive Properties, *Chem. Sci.*, 2022, **13**, 10725–10733; (c) M.-Y. Ran, S.-H. Zhou, W.-B. Wei, B.-X. Li,



X.-T. Wu, H. Lin and Q.-L. Zhu, Rational Design of a Rare-Earth Oxychalcogenide  $\text{Nd}_3[\text{Ga}_3\text{O}_3\text{S}_3][\text{Ge}_2\text{O}_7]$  with Superior Infrared Nonlinear Optical Performance, *Small*, 2023, **19**, 2300248; (d) H. Chen, M.-Y. Ran, S.-H. Zhou, X.-T. Wu,

H. Lin and Q.-L. Zhu, Simple yet extraordinary: super-polyhedra-built 3D chalcogenide framework of  $\text{Cs}_5\text{Ga}_9\text{S}_{16}$  with excellent infrared nonlinear optical performance, *Chin. Chem. Lett.*, 2023, **34**, 107838.

